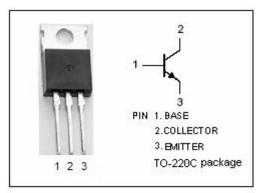


isc Silicon NPN Power Transistor

MJE15028

DESCRIPTION

- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)}= 120V(Min)
- · High Current Gain-Bandwidth Product-
- : f_T = 30MHz(Min)@ I_C = 0.5A
- DC current gain -
 - : h_{FE} = 40 (Min) @I_C= 3.0 A
 - : h_{FE} = 20 (Min) @I_C= 4.0 A
- Complement to Type MJE15029
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

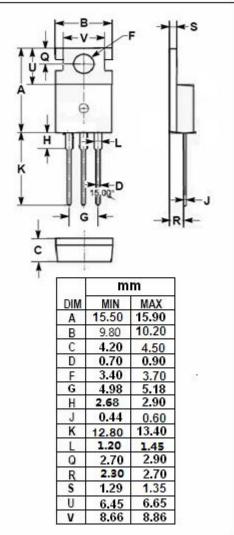
 Designed for use as high–frequency drivers in audio amplifiers.

ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	120	V	
V _{CEO}	Collector-Emitter Voltage	120	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current -Continuous	8	А	
Ісм	Collector Current-Peak	16	Α	
I _B	Base Current	2	А	
P _C	Collector Power Dissipation @T _a =25°C	2	W	
	Collector Power Dissipation @T _C =25°C	50		
T _j	Junction Temperature 150		°C	
T _{stg}	Storage Temperature	-65~150	$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	2.5	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient		°C/W





isc Silicon NPN Power Transistors

MJE15028

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 10mA ;I _B = 0	120		V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1A ;I _B = 0.1A		0.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 1A ; V _{CE} = 2V		1.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 120V; I _E = 0		10	μА
I _{CEO}	Collector Cutoff Current	V _{CE} = 120V; I _B = 0		0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		10	μА
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 2V	40		
h _{FE-2}	DC Current Gain	I _C = 2A ; V _{CE} = 2V	40		
h _{FE-3}	DC Current Gain	I _C = 3A ; V _{CE} = 2V	40		
h _{FE-4}	DC Current Gain	I _C = 4A ; V _{CE} = 2V	20		
f⊤	Current Gain-Bandwidth Product	I _C = 0.5A; V _{CE} = 10V; f _{test} = 10MHz	20		MHz

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